

www.vishay.com

Vishay Semiconductors

# Thyristor High Voltage, Phase Control SCR, 40 A



PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	35 A			
V <sub>DRM</sub> /V <sub>RRM</sub>	800 V, 1200 V			
V <sub>TM</sub>	1.45 V			
I <sub>GT</sub>	150 mA			
T <sub>J</sub>	-40 °C to +125 °C			
Package	TO-247AC 3L			
Circuit configuration	Single SCR			

#### **FEATURES**

- Designed and qualified according to JEDEC®-JESD 47
- Low IGT parts available
- 125 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



#### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding and battery charge

#### **DESCRIPTION**

The VS-40TPS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I <sub>T(AV)</sub>	Sinusoidal waveform	35	Δ.		
I <sub>RMS</sub>		55	A		
V <sub>RRM</sub> /V <sub>DRM</sub>		800 to 1200	V		
I <sub>TSM</sub>		600	A		
V <sub>T</sub>	40 A, T <sub>J</sub> = 25 °C	1.45	V		
dV/dt		1000	V/µs		
dl/dt		100	A/µs		
TJ		-40 to +125	°C		

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA			
VS-40TPS08A-M3	800	900				
VS-40TPS08-M3	800	900	10			
VS-40TPS12A-M3	1200	1300	10			
VS-40TPS12-M3	1200	1300				



<b>ABSOLUTE MAXIMUM RATINGS</b>					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 79 °C, 180° conduction half sine wav	е	35	
Maximum continuous RMS on-state current as AC switch	I <sub>T(RMS)</sub>			55	Α
Maximum peak, one-cycle	L	10 ms sine pulse, rated V <sub>RRM</sub> applied		500	
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage reapplied		600	
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	Initial $T_{.1} = T_{.1} max$ .	1250	A <sup>2</sup> s
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	ij – ijiilax.	1760	A <sup>2</sup> S
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied		17 600	A <sup>2</sup> √s
Low level value of threshold voltage	V <sub>T(TO)1</sub>			1.02	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	T 405.00			V
Low level value of on-state slope resistance	r <sub>t1</sub>	T <sub>J</sub> = 125 °C		9.74	mΩ
High level value of on-state slope resistance	r <sub>t2</sub>			7.50	
Maximum peak on-state voltage	$V_{TM}$	110 A, T <sub>J</sub> = 25 °C		1.85	V
Maximum rate of rise of turned-on current	dl/dt	T <sub>J</sub> = 25 °C		100	A/µs
Maximum holding current	I <sub>H</sub>	Anode supply = 6 V, resistive load, initial T	= 1 A, I <sub>T</sub> = 25 °C	200	
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T <sub>.I</sub> = 25 °C		300	
		$T_{J} = 25  ^{\circ}\text{C}$ $T_{J} = 125  ^{\circ}\text{C}$ $V_{R} = \text{Rated V}_{RRM}/V_{DRM}$		0.5	mA
Maximum reverse and direct leakage current	I <sub>RRM/</sub> I <sub>DRM</sub>			10	
Maximum rate of rise of off-state voltage 40TPS12A	a) (/d+	$T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ , $R_g$ - $k$ = 100 $\Omega$		500	\//··-
Maximum rate of rise of off-state voltage 40TPS12	dV/dt			1000	V/µs

TRIGGERING						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum peak gate power	P <sub>GM</sub>			10	W	
Maximum average gate power	P <sub>G(AV)</sub>			2.5	VV	
Maximum peak gate current	I <sub>GM</sub>			2.5	Α	
Maximum peak negative gate voltage	- V <sub>GM</sub>			10	V	
		T <sub>J</sub> = - 40 °C		4.0	V	
Maximum required DC gate voltage to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	2.5		
		T <sub>J</sub> = 125 °C	100iolivo ioaa	1.7		
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	270	mA	
Maximum vaguired DC gate august to triager		T <sub>J</sub> = 25 °C		150		
Maximum required DC gate current to trigger		T <sub>J</sub> = 125 °C		80		
		$T_J$ = 25 °C, for 40TPSAPbF and 40TPSA-M3		40		
Maximum DC gate voltage not to trigger for 40TPS12	$V_{GD}$	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value		0.25	V	
Maximum DC gate current not to trigger for 40TPS12	I <sub>GD</sub>			6	mA	
Maximum DC gate voltage not to trigger for 40TPS12A	$V_{GD}$	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value		0.15	V	
Maximum DC gate current not to trigger for 40TPS12A	I <sub>GD</sub>			1	mA	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stor temperature range	age	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +125	°C	
Maximum thermal resistand junction to case	ce,	R <sub>thJC</sub>	DC operation	0.6		
Maximum thermal resistand junction to ambient	Maximum thermal resistance, junction to ambient		R <sub>thJA</sub> DC operation		°C/W	
Maximum thermal resistant case to heatsink	ce,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque -	maximum			12 (10)	(lbf ⋅ in)	
				40TP	S08A	
Marking device			Coop of do TO 247AC 21	40TPS12A		
			Case style TO-247AC 3L	40TF	PS08	
				40TPS12		

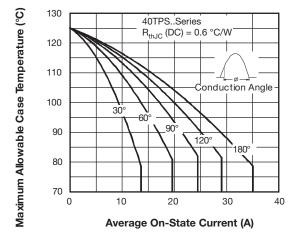


Fig. 1 - Current Rating Characteristics

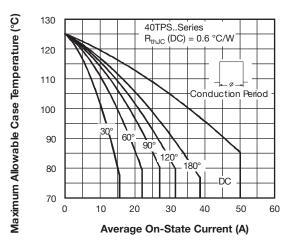


Fig. 2 - Current Rating Characteristics

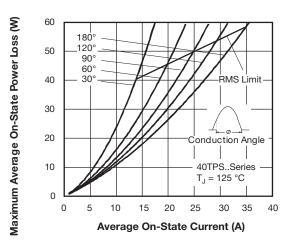


Fig. 3 - On-State Power Loss Characteristics

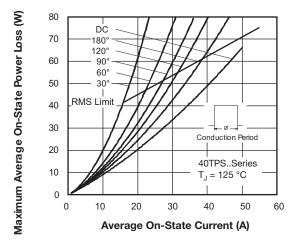


Fig. 4 - On-State Power Loss Characteristics



#### www.vishay.com

## Vishay Semiconductors

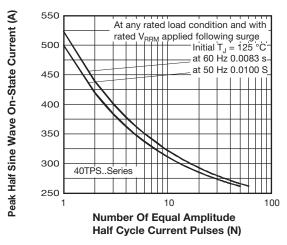


Fig. 5 - Maximum Non-Repetitive Surge Current

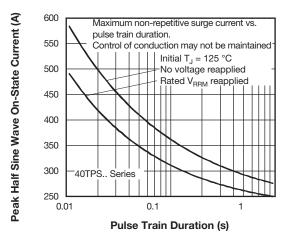


Fig. 6 - Maximum Non-Repetitive Surge Current

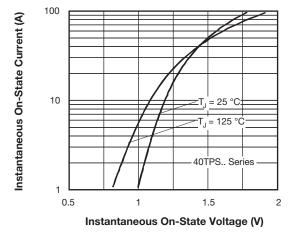


Fig. 7 - On-State Voltage Drop Characteristics



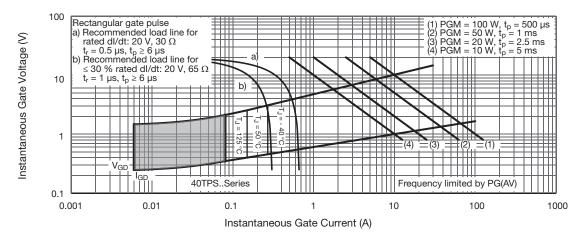


Fig. 8 - Gate Characteristics

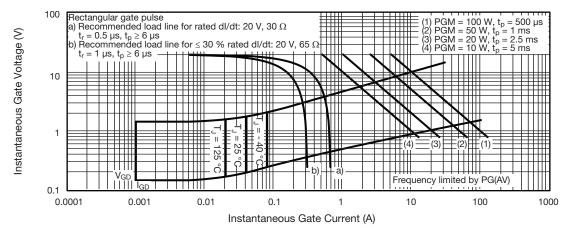


Fig. 9 - Gate Characteristics, 40TPS..A Series

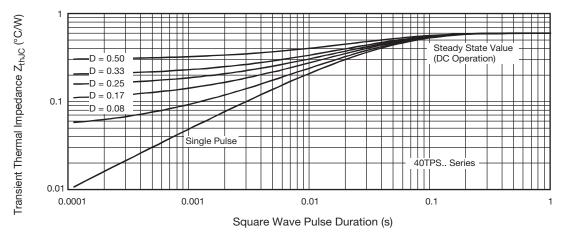
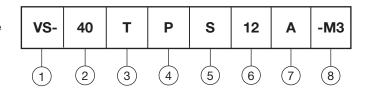


Fig. 10 - Thermal Impedance ZthJC Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

**2** - Current rating (40 = 40 A)

**3** - Circuit configuration:

T = thyristor

4 - Package:

P = TO-247AC 3L

5 - Type of silicon:

S = standard recovery rectifier

08 = 800 V12 = 1200 V

Voltage ratings

A = low I<sub>GT</sub> selection 40 mA maximum

• None = standard lgt selection

8 - Environmental digit:

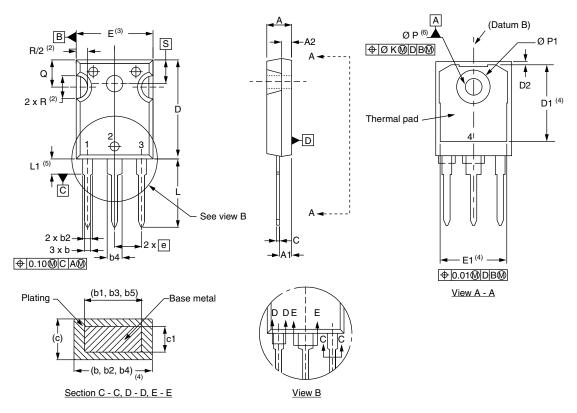
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-40TPS08A-M3	25	500	Antistatic plastic tubes			
VS-40TPS08-M3	25	500	Antistatic plastic tubes			
VS-40TPS12A-M3	25	500	Antistatic plastic tubes			
VS-40TPS12-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96138				
Part marking information	www.vishay.com/doc?95007			

### **TO-247AC 3L**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STINIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	Ì
Α	4.65	5.31	0.183	0.209		Ì
A1	2.21	2.59	0.087	0.102		Ì
A2	1.17	1.37	0.046	0.054		Ì
b	0.99	1.40	0.039	0.055		Ì
b1	0.99	1.35	0.039	0.053		Ì
b2	1.65	2.39	0.065	0.094		Ì
b3	1.65	2.34	0.065	0.092		Ì
b4	2.59	3.43	0.102	0.135		Ì
b5	2.59	3.38	0.102	0.133		Ì
С	0.38	0.89	0.015	0.035		Ì
c1	0.38	0.84	0.015	0.033		Ì
D	19.71	20.70	0.776	0.815	3	ĺ
D1	13.08	-	0.515	-	4	

SYMBOL	MILLIMETERS		INC	INCHES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.35	0.020	0.053		
Е	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØK	0.254		0.010			
L	14.20	16.10	0.559	0.634		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	7.39	-	0.291		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217	BSC		

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension Q



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

## Vishay:

<u>VS-40TPS08</u> <u>VS-40TPS08A</u> <u>VS-40TPS12A</u> <u>VS-40TPS12APBF</u> <u>VS-40TPS12PBF</u> <u>VS-40TPS08APBF</u> <u>VS-40TPS08APBF</u>